

Transient Voltage Suppressors for ESD Protection

General Description

The LESD8D7.0CBT5G is designed to protect voltage sensitive components from ESD and transient voltage events. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium.

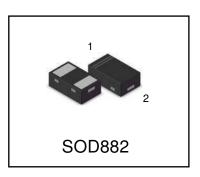
Applications

- Cellular phones
- Portable devices
- Digital cameras
- Power supplies

Features

- Small Body Outline Dimensions
- Low Body Height
- Peak Power up to 160 W @ 8 x 20µs Pulse
- Low Leakage
- Response Time is Typically < 1 ns
- ESD Rating of Class 3 per Human Body Model
- IEC61000 -4-2 Level 4 ESD Protection
- IEC61000 -4-4 Level 4 EFT Protection
- We declare that the material of product compliance with RoHS requirements and Halogen Free.
- Moisture Sensitivity Level-----Level 1

LESD8D7.0CBT5G





ORDERING INFORMATION

Device	Marking	Shipping		
LESD8D7.0CBT5G	R5	10000/Tape & Reel		

Absolute Ratings (T_{amb}=25°C)

Symbol	Parameter	Value	Units
P _{PP}	Peak Pulse Power (t _p = 8/20μs)	160	W
T_L	Maximum lead temperature for soldering during 10s	260	°C
T_{stg}	Storage Temperature Range	-55 to +150	°C
T _{op}	Operating Temperature Range	-40 to +125	°C
Tj	Maximum junction temperature	150	°C
	IEC61000-4-2 (ESD) air discharge contact discharge	±30 ±30	KV
	IEC61000-4-4 (EFT)	40	Α

Mar. 2020 Rev.B 1/4

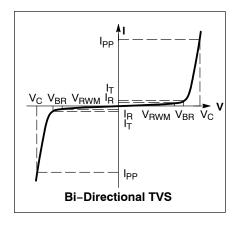


LESD8D7.0CBT5G

Electrical Characteristics

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Symbol	Parameter			
I _{PP}	Maximum Reverse Peak Pulse Current			
V _C	Clamping Voltage @ I _{PP}			
V_{RWM}	Working Peak Reverse Voltage			
I _R	Maximum Reverse Leakage Current @ V _{RWM}			
V_{BR}	Breakdown Voltage @ I _T			
Ι _Τ	Test Current			
P _{pk}	Peak Power Dissipation			
С	Capacitance @ V _R = 0 and f = 1.0 MHz			



Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.VF = 0.9V at IF = 10mA

Device	V _{RWM} (V)	I _R (uA) @ V _{RWM}		V)@ I _T ote 1)	I_	V _C (V) @ I _{PP} =3 A*	V _C (V) @ Max I _{PP} *	I _{PP} (A)*	P _{PK} (W)*	C (pF)
	Max	Max	Min	Max	mA	Max	Max	Max	Max	Тур
LESD8D7.0CBT5G	7.0	1.0	7.5	9.5	1.0	10.5	13	12	160	35

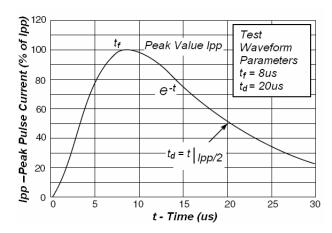
^{*}Surge current waveform per Figure 2.

1. V_{BR} is measured with a pluse test current I_T at an ambient temperature of 25 $^\circ\!\!\!\!$ C .

Mar. 2020 Rev.B 2/4



LESD8D7.0CBT5G



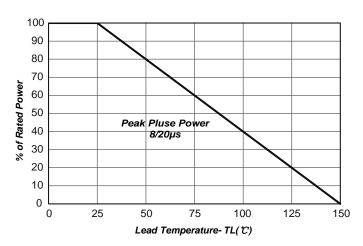


Fig 1. Pulse Waveform

Fig 2.Power Derating

Application Note

Electrostatic discharge (ESD) is a major cause of failure in electronic systems. Transient Voltage Suppressors (TVS) are an ideal choice for ESD protection. They are capable of clamping the incoming transient to a low enough level such that damage to the protected semiconductor is prevented.

Surface mount TVS offer the best choice for minimal lead inductance. They serve as parallel protection elements, connected between the signal line to ground. As the transient rises above the operating voltage of the device, the TVS becomes a low impedance path diverting the transient current to ground. The LESD8D7.0CT5G is the ideal board evel protection of ESD sensitive semiconductor components.

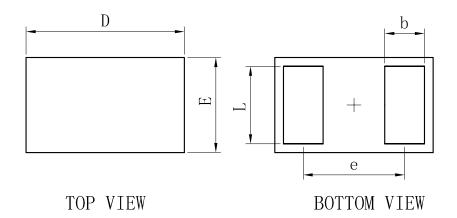
The tiny SOD882 package allows design flexibility in the design of high density boards where the space saving is at a premium. This enables to shorten the routing and contributes to hardening againt ESD.

Mar. 2020 Rev.B 3/4

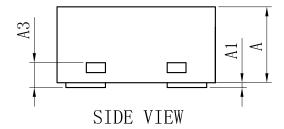


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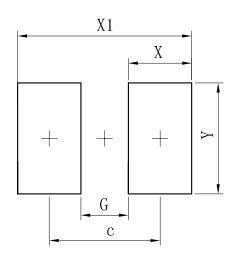
OUTLINE AND DIMENSIONS



	S0D882					
Dim	Min	Тур	Max			
D	0. 95	1.00	1.05			
Е	0. 55	0.60	0.65			
е	_	0.64	_			
L	0.44	0.49	0.54			
b	0. 20	0. 25	0.30			
A	0.43	0.48	0. 53			
A1	0	-	0.05			
A3 0. 127REF.						
All Dimensions in mm						



SOLDERING FOOTPRINT



Dimensions	(mm)
С	0.70
G	0.30
X	0.40
X1	1. 10
Y	0, 70

Mar. 2020 Rev.B 4/4